

## The Development of A Novel, Cold Electron Source Paper 328

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## **Objective**

The Objective of this development project was to determine if the microchannels within a microchannel plate could be modified to function as spontaneous electron emitters. Microchannel Plates (MCPs) are arrays of millions of single channel electron multipliers. These devices are routinely used in mass spectrometers to detect and amplify weak ion signals. MCPs are manufactured in sizes ranging from 2 – 150 mm in diameter.





# **Experimental Method**

Microchannel Plates operate on the principle of secondary electron emission. When a charged particle impinges on the input side of the channel with sufficient energy, a few secondary electrons are produced. The resultant electrons continue to cascade down the channel until a charge cloud exits the channel.

It was believed that by altering the microstructure within the channel, spontaneously emitted electrons could be produced, which would initiate the cascading of secondary electrons. By controlling the rate of spontaneous emission and the gain of the device, the emission current could be varied over a broad range.



### **Theory of Operation**



Electrons are spontaneously generated and amplified inside the channel when voltage is applied.



### **Theory of Operation**





Millions of channels are fused into virtually any shape and size to provide a uniform electron flux.



### Various Format Electron Generator Arrays





#### 50 x 8 mm



11 x 12 mm



18 mm

**40** mm



8 mm



### **Emission Current 18 mm Format**

Applied Voltage (Kv)

ELECTRO-OPTICS



1.5

### 50 x 8 mm Emission Current

1.00E-11

0

0.5

1

**BURL** ELECTRO-OPT



3

**ICS** 

Applied Voltage (kV)

2

2.5

### 10 x 12 mm Emission Current







### 8 mm Microtron<sup>™</sup> EGA







Applied Voltage (kV)



# EGA Electron Source Emission Current vs. Chamber Pressure, Backfill Argon





### ELECTROGEN<sup>TM</sup> Stability

#### % of initial Value





# Z-Stack 5 um pore, after 144 hours of operation







# Operational Life Time In PFTBA at 4 x 10<sup>-4</sup> torr



# Emission Uniformity and Beam Definition 50 x 8 mm Array, Z-Stack Configuration





Millimeters



### ELECTROGEN<sup>TM</sup> Turn-On Time



### Energy Distribution of Emitted Electrons, Z-Stack Configuration



Emission Current (Relative Scale Amps)





# **Common Ionization Methods**

Photo-Ionization

### Chemical Ionization

Field Ionization

Electron Impact



### Conventional Electron Impact Ionization Source Configuration





## **EGA Ionization Source Concept**





### Ion Sources





#### Conventional RGA Ion Source EGA Prototype Ion Source



### Residual Gas Analysis Taken With EGA Prototype Ion Source





### ELECTROGEN<sup>TM</sup> Advantages I

- "Cold" Ionization Source
- Large Emission Area
- Parallel Beam, Not Sensitive to Field Strength Changes
- High Density, Uniform Emission Pattern
- Fine Emission Level Control
- Won't Burn Out, Durable
- No Photon Noise



### ELECTROGEN<sup>TM</sup> Advantages II

- Low Maintenance, Frequent Cleaning not Required Because Of Cold Ionization
- No Heat-Up/Stabilization Time Required
- **Bi-Directional Emitter**
- Low Power Consumption (e-gun 38 W vs. EGA 0.024 W)
- Simple Single Voltage Supply Design
- No Raster Scanning Electronics Required



### **ELECTROGEN**<sup>TM</sup>

### **Specifications**

Emission Area	3 mm -150 mm dia
Electron Flux Density	<b>0 to 50</b> μ <b>A/cm<sup>2</sup></b> (Tunable)
Power Supply Voltage	to 3600V Max
<b>Current Required</b>	44 mA Max.
Max Bake Temp	300°C
Max Operating Temp	200°C
Uniformity	10%